



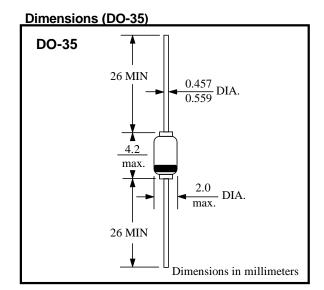
1N4448 SIGNAL DIODE

Absolute Maximum Ratings (Ta=25°C)

Items	Symbol	Ratings	Unit
Reverse Voltage	VR	75	V
Reverse Recovery	trr	4	ns
Power Dissipation 3.33mW/°C (25°C)	Р	500	mW
Forward Current	IF	500	mΑ
Junction Temp.	Tj	-65 to 175	∘C
Storage Temp.	Tstg	-65 to 175	°C

Mechanical Data

Items	Materials
Package	DO-35
Case	Hermetically sealed glass
Lead/Finish	Double stud/Solder Plating
Chip	Glass Passivated



Electrical Characteristics (Ta=25°C)

Ratings	Symbol	Ratings	Unit
Minimum Breakdown Voltage	BV		V
IR= 5.0uA		75	
IR= 100uA		100	
Peak Forward Surge Current PW= 1sec.	IFsurge	1.0	Α
Maximum Forward Voltage	VF		V
IF= 100mA		1.0	
Maximum Reverse Current	IR		uA
VR= 20V		0.025	
VR= 75V		5.0	
VR= 20V, Tj= 150∘C		50	
Maximum Junction Capacitance	Ci		pF
VR= 0, f= 1 MHz	•	4	,
Maximum Reverse Recovery Time	trr		ns
IF= 10mA, VR= 6V, IRR= 1mA, RL= 100Ω		4	